

Features

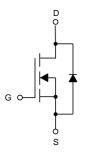
- High Density Cell Desihn for Ultra Low R_{DS(on)}
- Ultra Low Gate Charge
- Low Reverse Transfer Capacitance
- · Excellent Package for Good Heat Dissipation
- Fully Characterized Avalanche Voltage and Current
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient

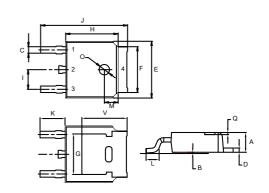
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	40	Α
Pulsed Drain Current	I _{DM}	160	Α
Single Pulse Avalanche Energy	E _{AS}	320	mJ
Total Power Dissipation	P _D	1.25	W

Internal Structure



N-CHANNEL MOSFET

DPAK(TO-252)



- 1. Gate
- 2,4. Drain
 - 3. Source

DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.087	0.094	2.20	2.40		
В	0.000	0.005	0.00	0.13		
С	0.026	0.034	0.66	0.86		
D	0.018	0.023	0.46	0.58		
Е	0.256	0.264	6.50	6.70		
F	0.201	0.215	5.10	5.46		
G	0.190		4.83		TYP.	
Н	0.236	0.244	6.00	6.20		
ı	0.086	0.094	2.18	2.39		
J	0.386	0.409	9.80	10.40		
K	0.114		2.9	90	TYP.	
L	0.055	0.067	1.40	1.70		
M	0.063		1.60		TYP.	
0	0.043	0.051	1.10	1.30		
Q	0.000	0.012	0.00	0.30		
V	0.211		5.3	35	TYP.	



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

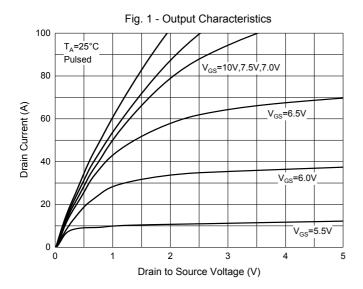
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics				1		I
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V
Gate-Source Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
Gate-Threshold Voltage ^(Note 1)	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1		2.5	V
Drain-Source On-Resistance ^(Note 1)	R _{DS(on)}	V _{GS} =10V, I _D =28A		14	17	mΩ
Forward Tranconductance ^(Note 1)	g _{FS}	V _{DS} =25V, I _D =28A	32			S
Dynamic Characteristics(Note 2))		"	•		
Input Capacitance	C _{iss}			3400		
Output Capacitance	C _{oss}	V_{DS} =30V, V_{GS} =0V,f=1MHz		290		pF
Reverse Transfer Capacitance	C _{rss}			221		
Total Gate Charge	Qg			94		nC
Gate-Source Charge	Q_{gs}	V_{DD} =30V, V_{GS} =10V, I_{D} =30A		16		
Gate-Drain Charge	Q_{gd}			24		
Turn-On Delay Time	t _{d(on)}			15		
Turn-On Rise Time	t _r	$V_{DD} = 30V, V_{GS} = 10V, R_G = 2.5\Omega,$		11		
Turn-Off Delay Time	t _{d(off)}	$I_D=2A$, $R_L=15\Omega$		52		ns
Turn-Off Fall Time	t _f			13		
Drain-Source Body Diode Cha	racteristi	cs		<u>, </u>	·	
Continuous Body Diode Current	I _S	T _c =25°C			40	Α
Pulsed Diode Forward Current	I _{SM}	1 _C -23 0			160	
Body Diode Voltage	V _{SD}	I _S =28A, V _{GS} =0V			1.2	V

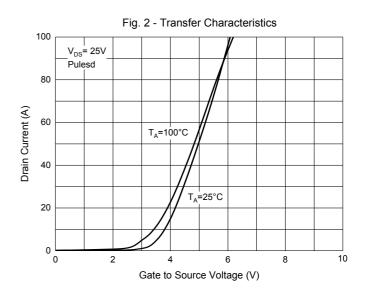
Note 1. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 1%.

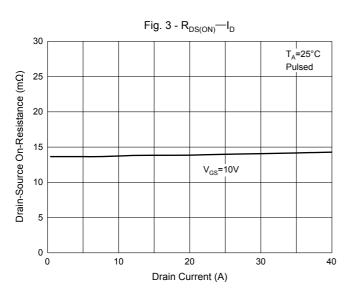
^{2.} Guaranteed by Design, Not Subject to Production Testing.

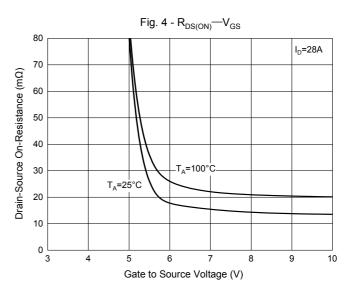


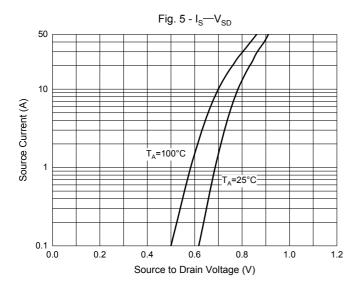
Curve Characteristics

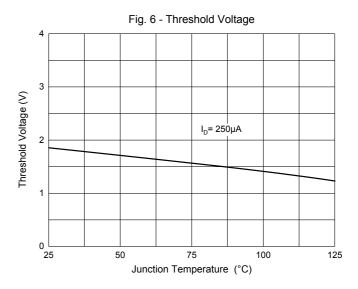














Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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